

Exact simulation of the diffraction of large, high-NA DOE-sections with $O(N \log N)$ time and memory resort

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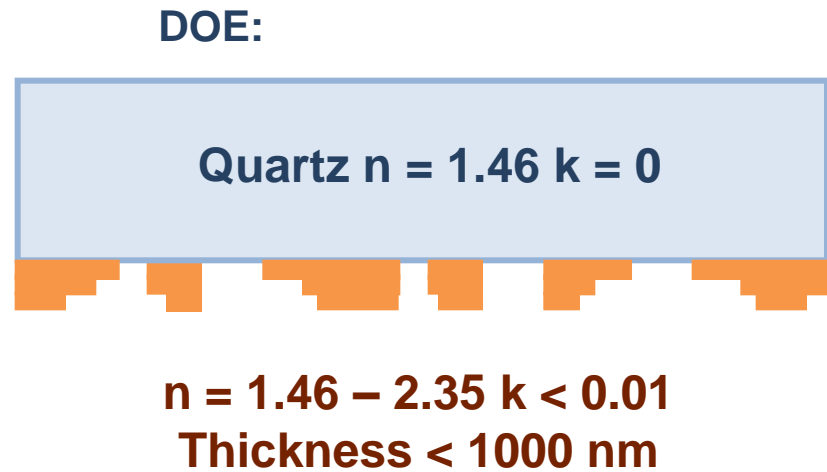
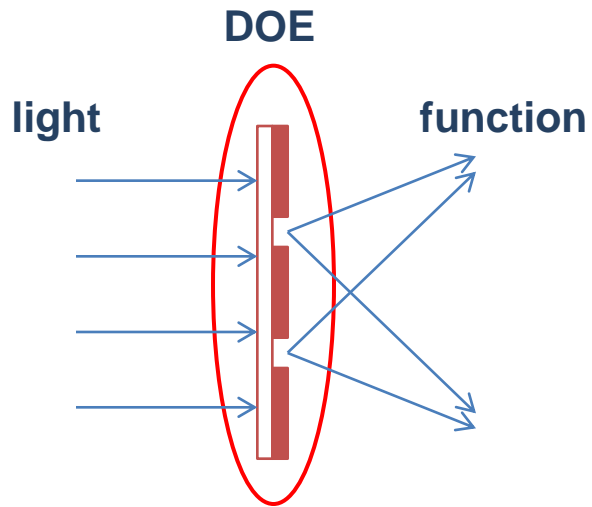
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OUTLINE

- **DOE simulation**
- **Generalized Source Method**
- **Three breakthroughs that make GSM ultrafast and memory sparing**
- **Numerical benchmarks**
- **Conclusions**

DOE SIMULATION



REQUIREMENTS

Requirements on a new method for today's objectives
in *DOE simulation*:

Rigorous

Fast and memory-sparing

Challenge:

DOE **reference** method $\stackrel{?}{\equiv}$ DOE fast **tool**

Current exact methods (FDTD, FMM (RCWA))
are **very far** from this objective

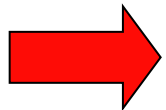
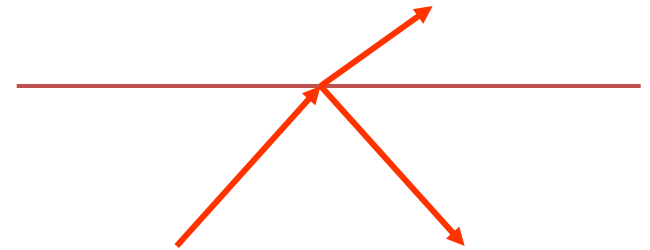
TYPE OF APPROACH

A DOE is a planar structure



Plane waves are a basic solutions

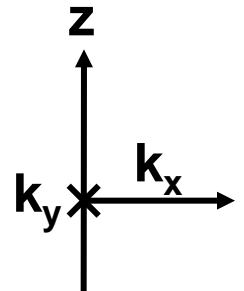
characterized by their in-plane wavevector projections k_x , k_y



An efficient resolution technique has to operate

in-plane in the reciprocal k -space k_x , k_y

in the direct space normally to the plane, along z



GENERALIZED SOURCE METHOD

The electromagnetic problem is characterized by the spatial permittivity distribution:

$$\varepsilon = \varepsilon(\mathbf{r})$$

1. Replace the initial problem with another one with $\varepsilon_b(\mathbf{r})$ which has an exact analytical solution for any source distribution:

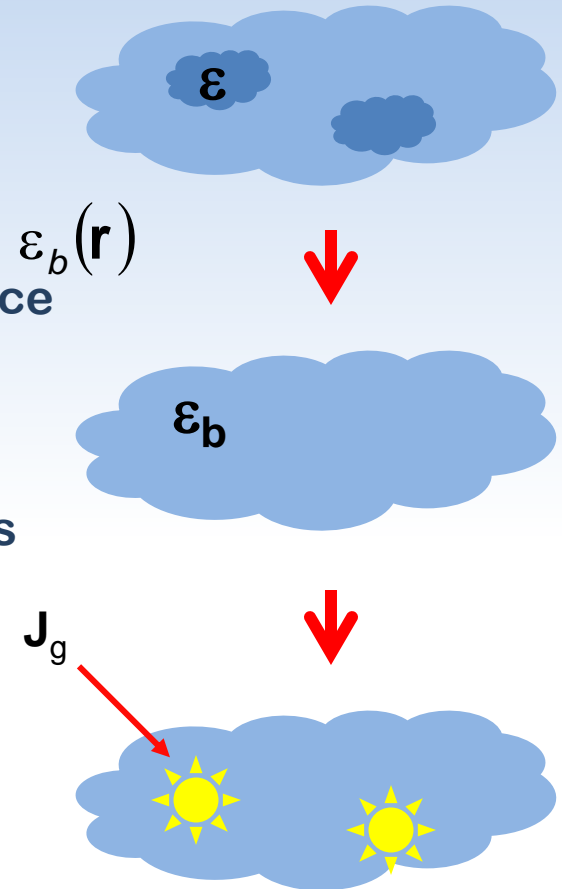
$$\nabla \times \nabla \times \mathbf{E} - \omega^2 \mu_0 \varepsilon_b(\mathbf{r}) \mathbf{E} = i\omega \mu_0 \mathbf{J} \quad \Rightarrow \quad \mathbf{E} = \mathfrak{N}_b(\mathbf{J})$$

2. Take all nonzero differences between permittivities as generalized sources

$$\mathbf{J}_g = -i\omega(\varepsilon - \varepsilon_b)\mathbf{E}$$

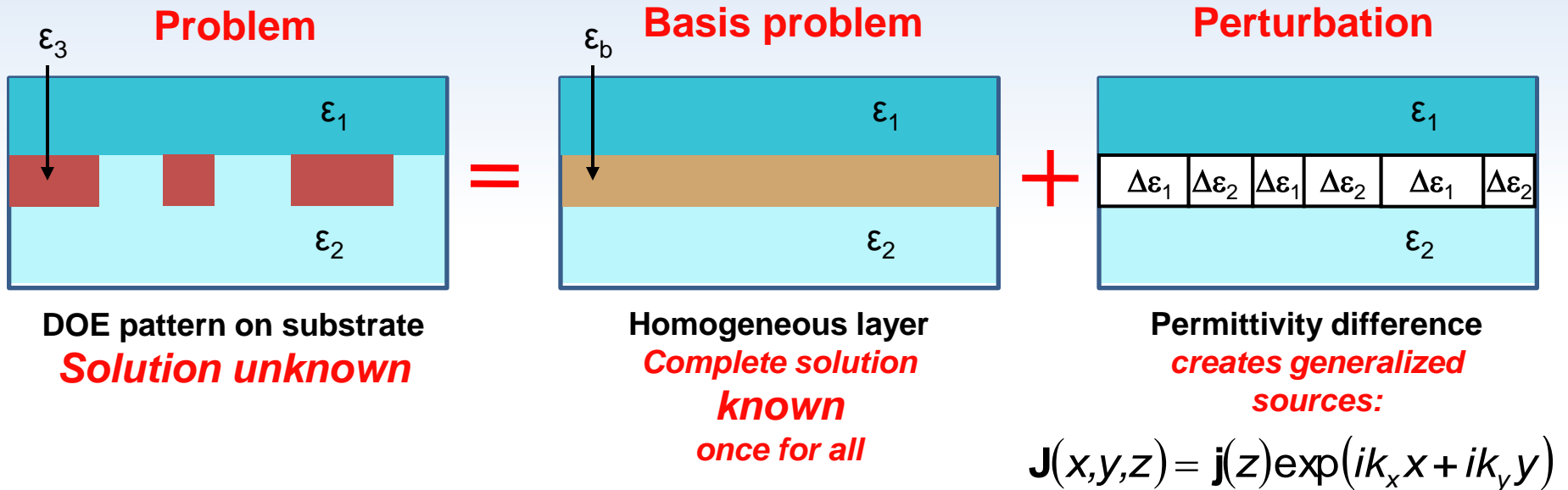
3. This leads to an implicit equation for unknown \mathbf{E}

$$\mathbf{E} = \mathbf{E}_0 - \mathfrak{N}_b[i\omega(\varepsilon - \varepsilon_b)\mathbf{E}]$$



¹A.V. Tishchenko, Generalized source method: new possibilities for waveguide and grating problems // Opt. Quantum Electron., 32, 1971-1980 (2000)

Example of a binary corrugation



INTEGRAL EQUATION

Maxwell equations are reduced finally
to the implicit integral equation:

$$\begin{pmatrix} \mathbf{a}_n^{e\pm}(z) \\ \mathbf{a}_n^{h\pm}(z) \end{pmatrix} = \delta_{n0} \begin{pmatrix} \mathbf{a}_{inc}^{e\pm}(z) \\ \mathbf{a}_{inc}^{h\pm}(z) \end{pmatrix} + \sum_{\alpha=x,y,z} \int_{-\infty}^{\infty} \left\{ \sum_{m=-\infty}^{\infty} \sum_{\beta=x,y,z} \mathbf{P}_{n\alpha}^{\pm} \mathbf{R}_{n\alpha}^{\pm}(z, z') \mathbf{V}_{nm}^{\alpha\beta}(z') \left[\mathbf{Q}_{m\beta}^{+} \begin{pmatrix} \mathbf{a}_m^{e+}(z') \\ \mathbf{a}_m^{h+}(z') \end{pmatrix} + \mathbf{Q}_{m\beta}^{-} \begin{pmatrix} \mathbf{a}_m^{e-}(z') \\ \mathbf{a}_m^{h-}(z') \end{pmatrix} \right] \right\} dz'$$

INTEGRAL EQUATION

Integral equation:

$$\begin{pmatrix} a_n^{e\pm}(z) \\ a_n^{h\pm}(z) \end{pmatrix} = \delta_{n0} \begin{pmatrix} a_{inc}^{e\pm}(z) \\ a_{inc}^{h\pm}(z) \end{pmatrix} + \sum_{\alpha=x,y,z} \int_{-\infty}^{\infty} \left\{ \sum_{m=-\infty}^{\infty} \sum_{\beta=x,y,z} P_{n\alpha}^{\pm} R_{n\alpha}^{\pm}(z, z') V_{nm}^{\alpha\beta}(z') \left[Q_{m\beta}^{+} \begin{pmatrix} a_m^{e+}(z') \\ a_m^{h+}(z') \end{pmatrix} + Q_{m\beta}^{-} \begin{pmatrix} a_m^{e-}(z') \\ a_m^{h-}(z') \end{pmatrix} \right] \right\} dz'$$

Incident field harmonics

INTEGRAL EQUATION

Integral equation:

$$\begin{pmatrix} a_n^{e\pm}(z) \\ a_n^{h\pm}(z) \end{pmatrix} = \delta_{n0} \begin{pmatrix} a_{inc}^{e\pm}(z) \\ a_{inc}^{h\pm}(z) \end{pmatrix} + \sum_{\alpha=x,y,z} \int_{-\infty}^{\infty} \left\{ \sum_{m=-\infty}^{\infty} \sum_{\beta=x,y,z} P_{n\alpha}^{\pm} R_{n\alpha}^{\pm}(z, z') V_{nm}^{\alpha\beta}(z') \left[Q_{n\beta}^{+} \begin{pmatrix} a_m^{e+}(z') \\ a_m^{h+}(z') \end{pmatrix} + Q_{n\beta}^{-} \begin{pmatrix} a_m^{e-}(z') \\ a_m^{h-}(z') \end{pmatrix} \right] \right\} dz'$$

Unknown amplitudes of TE- and TM-polarized harmonics

INTEGRAL EQUATION

Integral equation:

$$\begin{pmatrix} a_n^{e\pm}(z) \\ a_n^{h\pm}(z) \end{pmatrix} = \delta_{n0} \begin{pmatrix} a_{inc}^{e\pm}(z) \\ a_{inc}^{h\pm}(z) \end{pmatrix} + \sum_{\alpha=x,y,z} \int_{-\infty}^{\infty} \left\{ \sum_{m=-\infty}^{\infty} \sum_{\beta=x,y,z} P_{n\alpha}^{\pm} R_{n\alpha}^{\pm}(z, z') V_{nm}^{\alpha\beta}(z') \left[Q_{m\beta}^+ \begin{pmatrix} a_m^{e+}(z') \\ a_m^{h+}(z') \end{pmatrix} + Q_{m\beta}^- \begin{pmatrix} a_m^{e-}(z') \\ a_m^{h-}(z') \end{pmatrix} \right] \right\} dz'$$

Transition matrix from TE- and TM-harmonics amplitudes to x-, y- and z-components of the electric field

$$Q_n^{\pm} = \begin{pmatrix} \frac{k_{y0}}{\gamma_n} & \mp \frac{k_{xn} k_{zn}}{\omega \epsilon_b \gamma_n} \\ -\frac{k_{xn}}{\gamma_n} & \mp \frac{k_{y0} k_{zn}}{\omega \epsilon_b \gamma_n} \\ 0 & \frac{\gamma_n}{\omega \epsilon_b} \end{pmatrix}$$

INTEGRAL EQUATION

Integral equation:

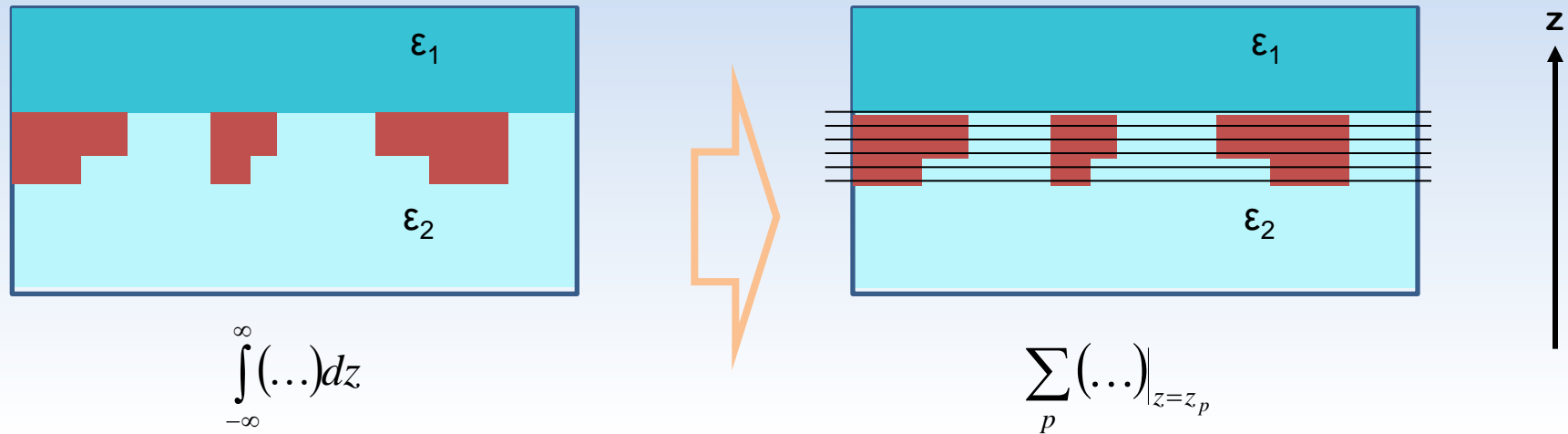
$$\begin{pmatrix} a_n^{e\pm}(z) \\ a_n^{h\pm}(z) \end{pmatrix} = \delta_{n0} \begin{pmatrix} a_{inc}^{e\pm}(z) \\ a_{inc}^{h\pm}(z) \end{pmatrix} + \sum_{\alpha=x,y,z} \int_{-\infty}^{\infty} \left\{ \sum_{m=-\infty}^{\infty} \sum_{\beta=x,y,z} \mathbf{P}_{n\alpha}^{\pm} \mathbf{R}_{m\alpha}^{\pm}(z, z') \mathbf{V}_{nm}^{\alpha\beta}(z') \left[\mathbf{Q}_{m\beta}^+ \begin{pmatrix} a_m^{e+}(z') \\ a_m^{h+}(z') \end{pmatrix} + \mathbf{Q}_{m\beta}^- \begin{pmatrix} a_m^{e-}(z') \\ a_m^{h-}(z') \end{pmatrix} \right] \right\} dz'$$

Transition matrix from x-, y- and z-components of the electric field to TE- and TM-harmonics amplitudes

$$\mathbf{P}_n^{\pm} = \begin{pmatrix} -\frac{\omega\mu_0 k_{y0}}{2\gamma_n k_{zn}} & \frac{\omega\mu_0 k_{xn}}{2\gamma_n k_{zn}} & 0 \\ \pm \frac{k_{xn}}{2\gamma_n} & \pm \frac{k_{y0}}{2\gamma_n} & -\frac{\gamma_n}{2k_{zn}} \end{pmatrix}$$

LINEAR SYSTEM OF ALGEBRAIC EQUATIONS

Along z the integral is divided into slices:



The resulting equation is written in the form

$$\mathbf{a}_n^\pm(z_1, z_2) = \delta_{n0} \mathbf{a}_n^{inc\pm}(z_1, z_2) + \sum_{\alpha=x,y,z} \sum_{\beta=x,y,z} \mathbf{T}_{nq}^\pm \mathbf{P}_{n\alpha}^\pm \mathbf{V}_{nmq}^{\alpha\beta} \mathbf{Q}_{m\beta}^\pm \left(\mathbf{A}_{nmpq}^{\pm\pm} \right)^{-1} \delta_{m0} \mathbf{a}_{nq}^{inc\pm}(z_1, z_2)$$

Where the *final matrix to be inverted* is

$$\mathbf{A}_{nmpq}^{\pm\pm} = \mathbf{I}_{nmpq}^{\pm\pm} - \sum_{\alpha=x,y,z} \sum_{\beta=x,y,z} \mathbf{R}_{npq}^\pm \mathbf{P}_{n\alpha}^\pm \mathbf{V}_{nmq}^{\alpha\beta} \mathbf{Q}_{m\beta}^\pm$$

LINEAR SYSTEM OF ALGEBRAIC EQUATIONS

$$A_{nmpq}^{\pm\pm} = I_{nmpq}^{\pm\pm} - \sum_{\alpha=x,y,z} \sum_{\beta=r,s,z} R_{npq}^{\pm} P_{n\alpha}^{\pm} V_{nmq}^{\alpha\beta} Q_{m\beta}^{\pm}$$

Matrix containing exponential factors that describe the wave propagation along z-axis

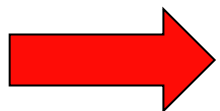
$$R_{npq}^{(e,h)(++)} = \Delta h \left[\theta_{p-q}^+ + \frac{r_n^{(L)e,h} r_n^{(U)e,h} \exp(2ik_{nz}h)}{1 - r_n^{(L)e,h} r_n^{(U)e,h} \exp(2ik_{nz}h)} \right] \exp[ik_{nz}\Delta h(p-q)]$$

$$R_{npq}^{(e,h)(+-)} = \Delta h \frac{r_n^{(L)e,h} \exp[ik_{nz}\Delta h(2N_L + 1 - p - q)]}{1 - r_n^{(L)e,h} r_n^{(U)e,h} \exp(2ik_{nz}h)}$$

$$R_{npq}^{(e,h)(-+)} = \Delta h \frac{r_n^{(U)e,h} \exp[ik_{nz}\Delta h(p + q - 1)]}{1 - r_n^{(L)e,h} r_n^{(U)e,h} \exp(2ik_{nz}h)}$$

$$R_{npq}^{(e,h)(--)} = \Delta h \left[\theta_{p-q}^- + \frac{r_n^{(L)e,h} r_n^{(U)e,h} \exp(2ik_{nz}h)}{1 - r_n^{(L)e,h} r_n^{(U)e,h} \exp(2ik_{nz}h)} \right] \exp[-ik_{nz}\Delta h(p-q)]$$

The 1st clue for ultra-fast computing:
Despite multiple reflections at interfaces matrix R keeps a Toeplitz structure



Fast numerical techniques applicable

DISCONTINUOUS PERMITTIVITY

3D boundary conditions affect matrix multiplications

$$\mathbf{J} = -i\omega(\mathbf{D} - \mathbf{D}_b)$$

↙ ↘

$$[\varepsilon]_{n-m} (E_{\parallel})_m = (D_{\parallel})_n \quad (E_{\perp})_n = \begin{bmatrix} 1 \\ -\varepsilon \end{bmatrix}_{n-m} (D_{\perp})_m$$

2nd clue for ultra-fast computing:

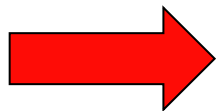
Matrix containing Fourier components of

permittivity

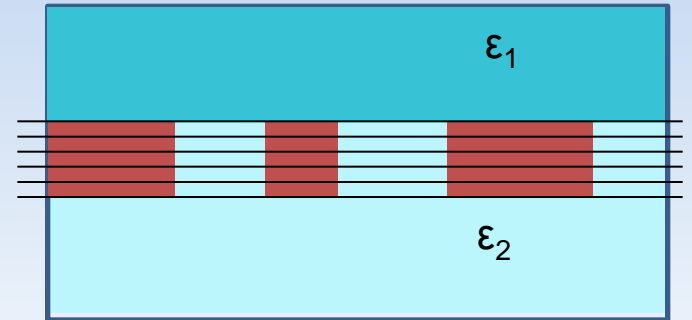
fields

local slope functions of boundaries

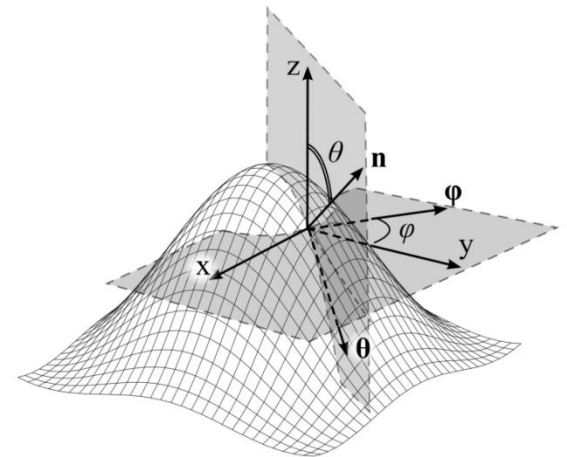
has Toeplitz structure



High accuracy achievable



FFT of 3D boundary condition functions



Last task: inversion of matrix A

$$A_{nmpq}^{\pm\pm} = I_{nmpq}^{\pm\pm} - \sum_{\alpha=x,y,z} \sum_{\beta=x,y,z} R_{npq}^{\pm} P_{n\alpha}^{\pm} V_{nmq}^{\alpha\beta} Q_{m\beta}^{\pm}$$

Assuming

number of slices: 100

number of diffraction orders: 100 and 100

 size of matrix A is $\sim 10^6$!!

3rd clue for ultra-fast computing:

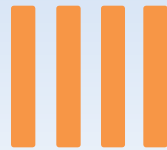
GMRES resolves a linear system in Krylov space in a few tens of iterative multiplications of a matrix by a vector

 **Fast and stable convergence attained**

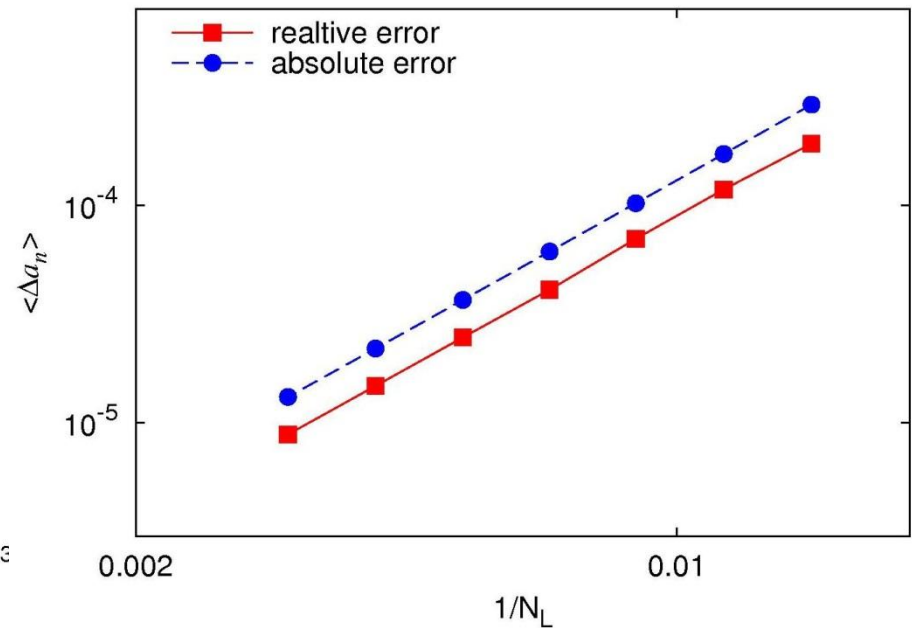
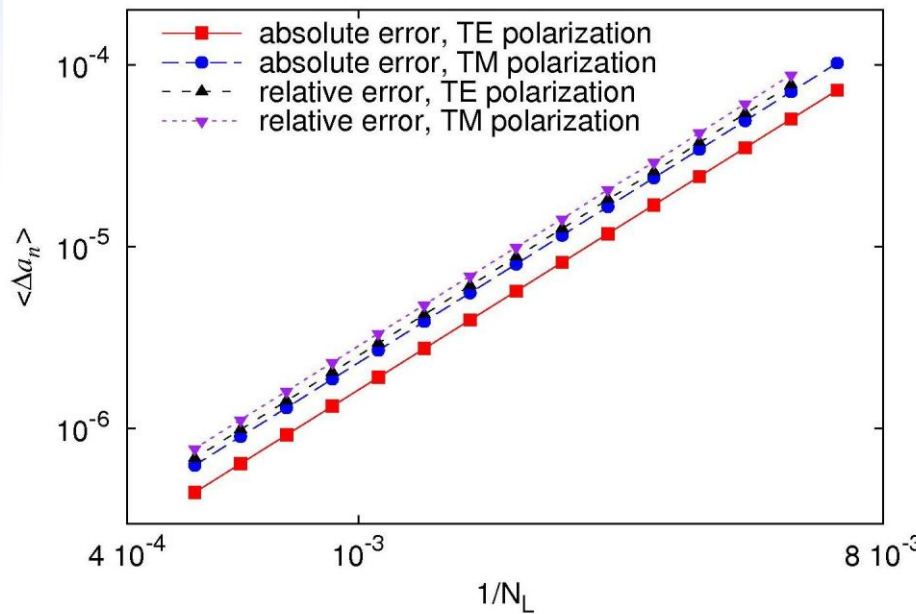
NUMERICAL BENCHMARKS

Comparison with Fourier-modal method (FMM, RCWA) versus number of slices N_L

1D grating



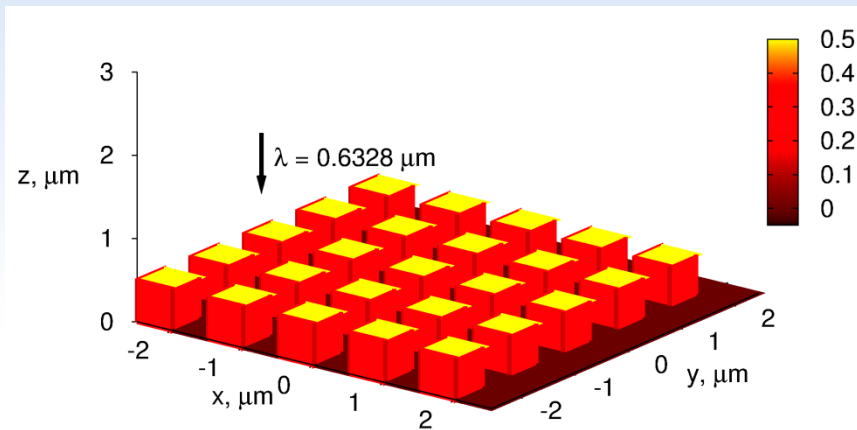
2D grating



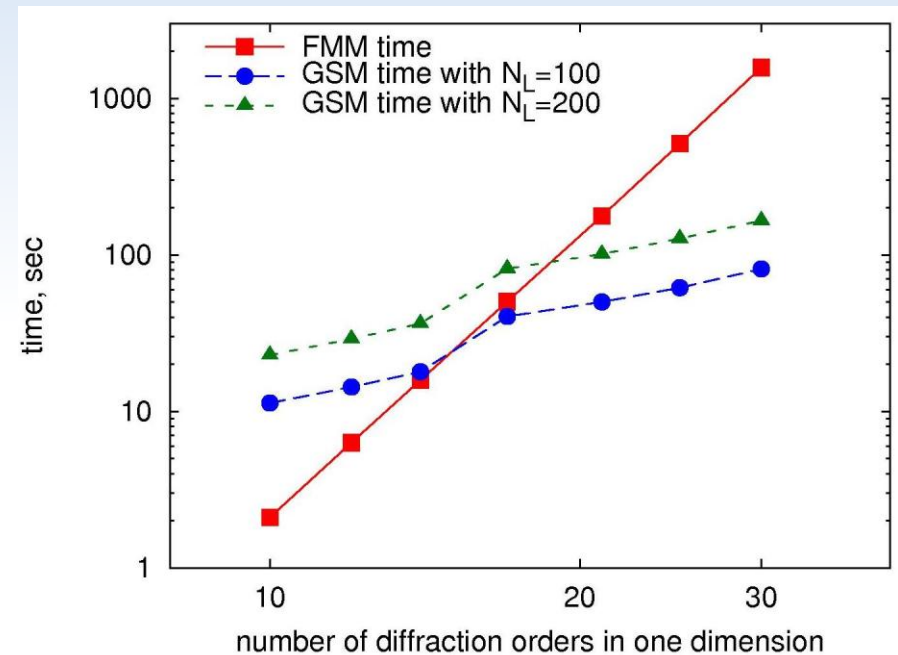
The dependencies resemble each other for different types of structures

NUMERICAL BENCHMARKS

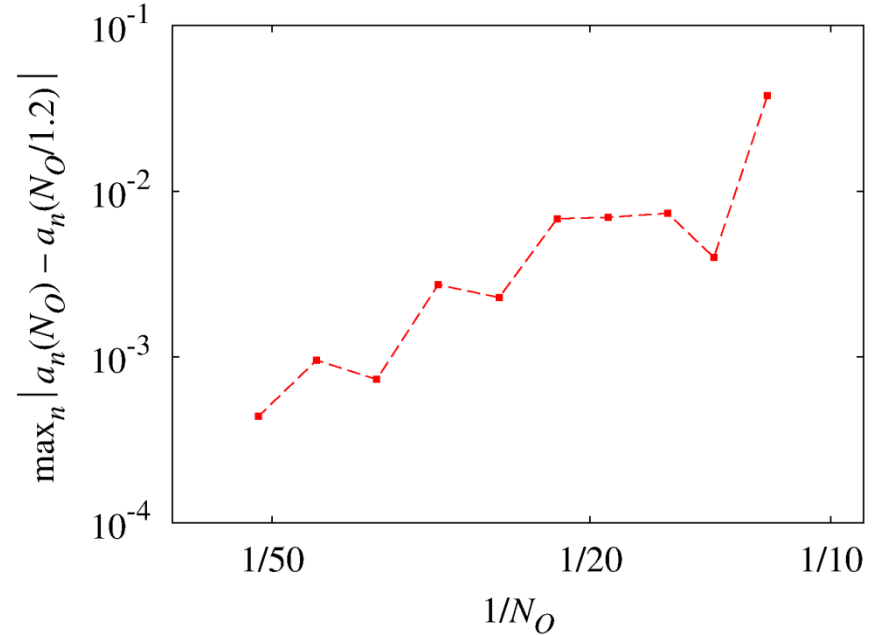
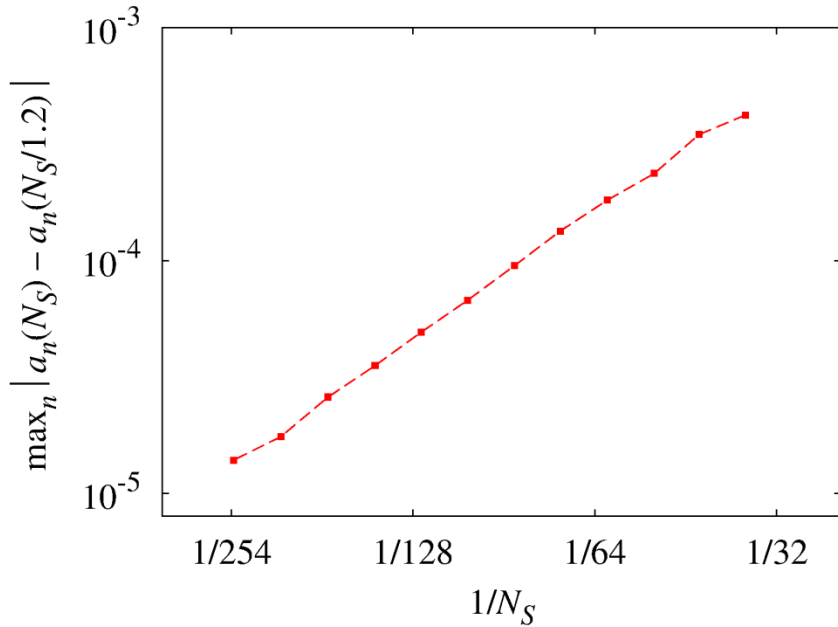
Comparison with Fourier-modal method (FMM, RCWA):



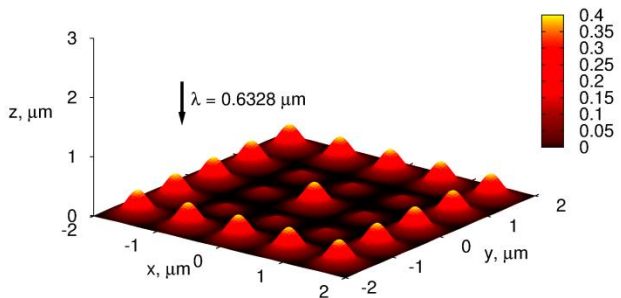
2D lamellar grating



NUMERICAL BENCHMARKS

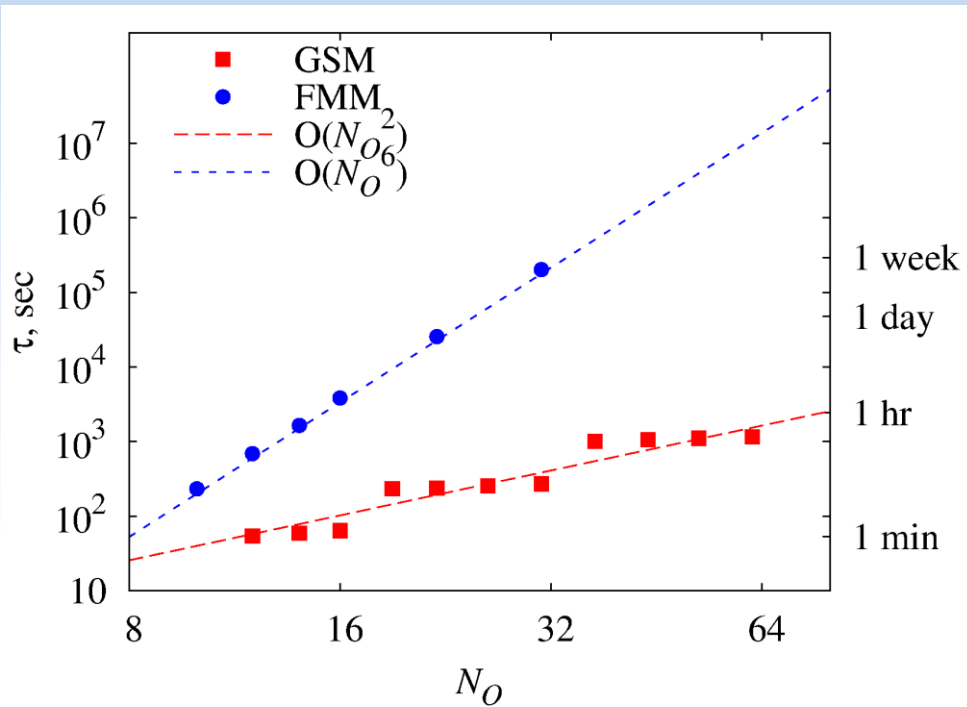


Convergence versus number of slices and diffraction orders

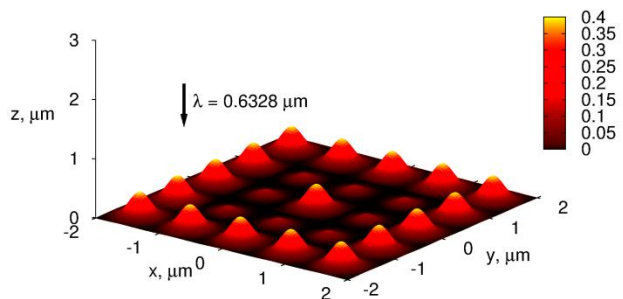


Period: 4 μm
Depth: 0.4 μm
Wavelength: 0.633 μm
DOE refractive index: 2.1
Cover refractive index: 1.0

NUMERICAL BENCHMARKS



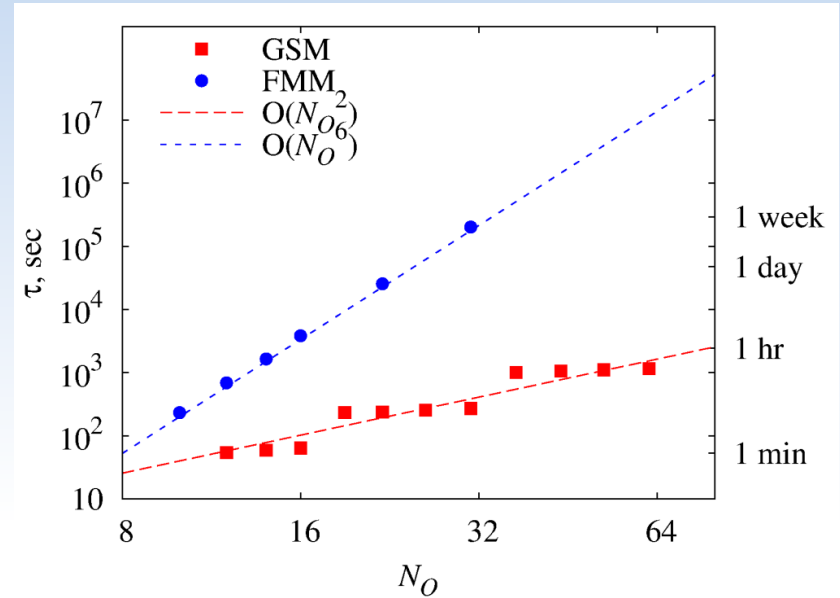
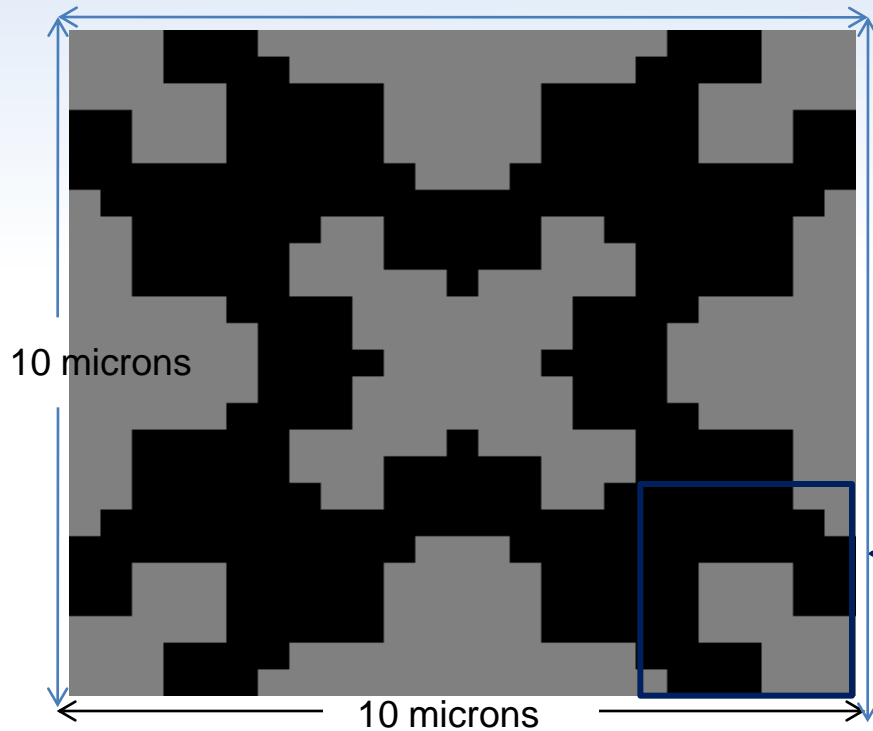
Processor 2.5 GHz
Memory 4 GB (Windows OS)



Period: 4 μm
Depth: 0.4 μm
Wavelength: 0.6328 μm
DOE refractive index: 2.1
Cover refractive index: 1.0

NUMERICAL BENCHMARKS

GSM needs 16 Gb of computer memory to calculate such DOE part with accuracy better than 10^{-3}



FMM fails to calculate more than this field because of memory limit

Parallel calculation by a GPU reduces 1 hour to 2-3 minutes!

CONCLUSION & PERSPECTIVES

- ✓ **The GSM breaks through the time & memory limits of existing exact methods.**
- ✓ **The GSM permits exact modeling to invade the land occupied by scalar methods**
- ✓ **It makes it in three important application fields of diffraction/scattering:**
 - **Reticle and wafer latent image in advanced photolithography**
 - **Scattering layers for light extraction from (O)LEDs**
 - **Diffraction optics, e.g., high NA diffraction lenses**

As from now on a big effort is needed to adapt and optimize the method to various application domain (*ref. Th. Kämpfe presentation in this conference*)

THANK YOU!